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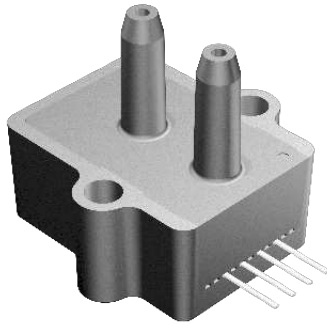
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Amplified Middle Pressure Sensors



Features

- 0 to ± 0.3 to 0 to 150 psi Pressure Ranges
- Ratiometric 4V Output
- Temperature Compensated
- Calibrated Zero and Span

Applications

- Medical Instrumentation
- Environmental Instrumentation
- HVAC Instrumentation

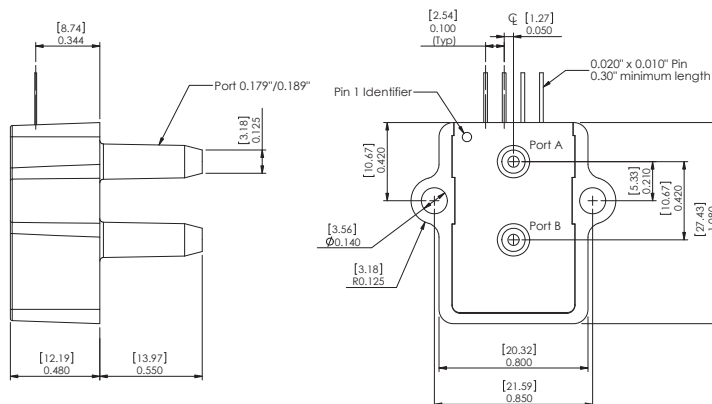
General Description

The Amplified line of middle pressure sensors are based upon a proprietary package technology to reduce errors. This model provides a ratiometric 4-volt output with superior output characteristics. The sensor housing has been designed specifically to reduce package induced parasitic stress and strain. In addition the sensor utilizes a silicon, micromachined, stress concentration enhanced structure to provide a very linear output to measured pressure.

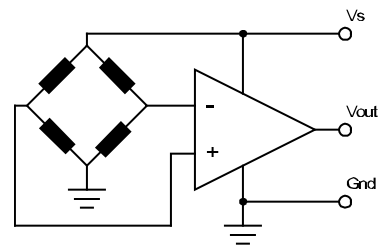
These calibrated and temperature compensated sensors give an accurate and stable output over a wide temperature range. Each sensor is internally compensated using an ASIC compensation technique. This series is intended for use with non-corrosive, non-ionic working fluids such as air, dry gases and the like.

The output of the device is ratiometric to the supply voltage over a supply voltage range of 4.5 to 5.5 volts.

Physical Dimensions



Equivalent Circuit



- pin 1: Vsupply**
- pin 2: Common**
- pin 3: Voutput**
- pin 4: do not connect**

Approvals

MKT	DATE	MFG	DATE	ENG	DATE	QA	DATE
<input type="checkbox"/> As Is <input type="checkbox"/> With Change		<input type="checkbox"/> As Is <input type="checkbox"/> With Change		<input type="checkbox"/> As Is <input type="checkbox"/> With Change		<input type="checkbox"/> As Is <input type="checkbox"/> With Change	



Pressure Sensor Ratings

Supply Voltage, V_s	+4.5 to +5.5 Vdc
Common-mode pressure	-10 to +10 psig
Lead Temperature, max (soldering 2-4 sec.)	250°C

Environmental Specifications

Temperature Ranges	
Compensated	5 to 50° C
Operating	-25 to 85° C
Storage	-40 to 125° C
Humidity Limits	0 to 95% RH (non condensing)

Standard Pressure Ranges

Part Number	Operating Pressure	Nominal Span	Proof Pressure	Burst Pressure
0.3 PSI-D-4V	±0.3 PSI	±2 V	5 PSI	10 PSI
0.3 PSI-G-4V	0 - 0.3 PSI	4 V	5 PSI	10 PSI
1 PSI-D-4V	±1 PSI	±2 V	5 PSI	10 PSI
1 PSI-G-4V	0 - 1 PSI	4 V	5 PSI	10 PSI
2.5 PSI-D-4V	±2.5 PSI	±2 V	10 PSI	20 PSI
2.5 PSI-G-4V	0 - 2.5 PSI	4V	10 PSI	20 PSI
5 PSI-D-4V	± 5 PSI	±2 V	15 PSI	30 PSI
5 PSI-G-4V	0 - 5 PSI	4 V	15 PSI	30 PSI
15 PSI-A-4V	0 - 15 PSIA	4 V	45 PSI	60 PSI
15 PSI-D-4V	±15 PSI	±2 V	45 PSI	60 PSI
15 PSI-G-4V	0 - 15 PSI	4 V	45 PSI	60 PSI
30 PSI-A-4V	0 - 30 PSIA	4 V	60 PSI	60 PSI
30 PSI-D-4V	±30 PSI	±2 V	60 PSI	60 PSI
30 PSI-G-4V	0 - 30 PSI	4 V	60 PSI	100 PSI
100 PSI-A-4V	0 - 100 PSI	4V	150 PSI	150 PSI
100 PSI-D-4V	±100 PSI	±2 V	150 PSI	150 PSI
100 PSI-G-4V	0 - 100 PSI	4V	150 PSI	150 PSI
150 PSI-D-4V	±150 PSI	±2 V	200 PSI	200 PSI
150 PSI-G-4V	0 - 150 PSI	4V	200 PSI	200 PSI
BARO-A-4V	600 - 1100 mbarA	4V	45 PSI	60 PSI

Performance Characteristics for 0.3 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±40.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±2.0	%FSS

Performance Characteristics for 0.3 PSI-G-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±40.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±2.0	%FSS

Performance Characteristics for 1 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±40.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for: 1 PSI-G-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Output Span, NOTE 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±40.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 2.5 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS



Performance Characteristics for: 2.5 PSI-G-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Output Span, NOTE 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for: 5 PSI-D-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Output Span, NOTE 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for: 5 PSI-G-4V

Parameter, NOTE 1	Minimum	Nominal	Maximum	Units
Output Span, NOTE 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 15 PSI-A-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero absolute pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 15 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 15 PSI-G-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 30 PSI-A-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero absolute pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 30 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS



Performance Characteristics for 30 PSI-G-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 100 PSI-A-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero absolute pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 100 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 100 PSI-G-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 150 PSI-D-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	±1.90	±2.0	±2.10	V
Offset Voltage @ zero differential pressure	2.15	2.25	2.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for 150 PSI-G-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Span, note 4 (FSS)	3.90	4.0	4.10	V
Offset Voltage @ zero gage pressure	0.15	0.25	0.35	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	--	±0.5	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Performance Characteristics for BARO-A-4V

Parameter, note 1	Minimum	Nominal	Maximum	Units
Output Voltage @ 1,100 mbar	4.20	4.25	4.30	V
Output Voltage @ 600 mbar	0.20	0.25	0.30	V
Offset Temperature Shift, note 2	--	--	±20.0	mV
Linearity, hysteresis error, note 3	--	0.05	±0.25	%FSS
Span Temperature Shift, note 2	--	--	±1.0	%FSS

Pressure Response: for any pressure applied the response time to get to 90% of pressure applied is typically less than 500 useconds.

Specification Notes

NOTE 1: ALL PARAMETERS ARE MEASURED AT 5.0 VOLT EXCITATION, FOR THE NOMINAL FULL SCALE PRESSURE AND ROOM TEMPERATURE UNLESS OTHERWISE SPECIFIED. PRESSURE MEASUREMENTS ARE WITH POSITIVE PRESSURE APPLIED TO PORT B. ABSOLUTE DEVICES REQUIRE PRESSURE TO BE APPLIED TO PORT A.

NOTE 2: SHIFT IS RELATIVE TO 25°C OVER THE COMPENSATED TEMPERATURE RANGE.

NOTE 3: MEASURED AT ONE-HALF FULL SCALE RATED PRESSURE USING BEST STRAIGHT LINE CURVE FIT.

NOTE 4: THE SPAN IS THE ALGEBRAIC DIFFERENCE BETWEEN FULL SCALE OUTPUT VOLTAGE AND THE OFFSET VOLTAGE.

